Pb Free Product



NCE0110AK

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE0110AK uses advanced trench technology and design to provide excellent R_{DS(ON)} with low gate charge. It can be used in a wide variety of applications.

General Features

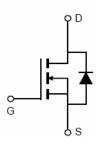
- V_{DS} =100V,I_D =10A
 - $R_{DS(ON)} < 130 \text{m}\Omega$ @ $V_{GS} = 10 \text{V}$ (Typ:95m Ω)
 - $R_{DS(ON)}$ < 140m Ω @ V_{GS} =4.5V (Typ:100m Ω)
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!

100% AVds TESTED!



Schematic diagram



Marking and pin assignment



TO-252-2L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE0110AK	NCE0110 AK	TO-252-2L	-	-	-

Absolute Maximum Ratings (T_c=25°Cunless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	100	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I _D	10	Α
Drain Current-Continuous(T _C =100°C)	I _D (100°ℂ)	7	А
Pulsed Drain Current	I _{DM}	24	А
Maximum Power Dissipation	P _D	40	W
Derating factor		0.27	W/°C
Single pulse avalanche energy (Note 5)	E _{AS}	20	mJ
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 175	$^{\circ}$

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NCE0110AK

Thermal Characteristic

Electrical Characteristics (T_C=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit	
Off Characteristics							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	100	110	-	V	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V,V _{GS} =0V	-	-	1	μΑ	
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA	
On Characteristics (Note 3)	<u> </u>		•				
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1.0	1.5	2.0	V	
Drain Course On State Begintenes	R _{DS(ON)}	V _{GS} =10V, I _D =10A	-	95	130		
Drain-Source On-State Resistance		V _{GS} =10V, I _D =8A		100	140	mΩ	
Forward Transconductance	g FS	V _{DS} =25V,I _D =6A	3.5	-	-	S	
Dynamic Characteristics (Note4)	<u> </u>		•				
Input Capacitance	C _{lss}	\/ -50\/\/ -0\/	-	900	-	PF	
Output Capacitance	Coss	V_{DS} =50V, V_{GS} =0V, F=1.0MHz	-	37	-	PF	
Reverse Transfer Capacitance	C _{rss}	F=1.UIVIDZ	-	27	-	PF	
Switching Characteristics (Note 4)	<u>.</u>						
Turn-on Delay Time	t _{d(on)}		-	11	-	nS	
Turn-on Rise Time	t _r	V_{DD} =50V, R_L =15 Ω	-	7.4	-	nS	
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{G} =2.5 Ω	-	35	-	nS	
Turn-Off Fall Time	t _f		-	9.1	-	nS	
Total Gate Charge	Qg)/ 50\/ L 40A	-	24		nC	
Gate-Source Charge	Q _{gs}	$V_{DS}=50V,I_{D}=10A,$ $V_{GS}=10V$	-	3.2	-	nC	
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	6	-	nC	
Drain-Source Diode Characteristics	<u> </u>		•				
Diode Forward Voltage (Note 3)	V_{SD}	V _{GS} =0V,I _S =10A	-	-	1.2	V	
Diode Forward Current (Note 2)	Is		-	-	10	Α	
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF =10A	-	21		nS	
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	97		nC	
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)					

Notes:

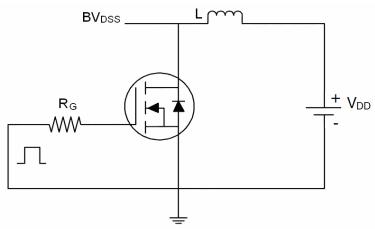
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, $t \le 10$ sec.
- **3.** Pulse Test: Pulse Width $\leq 300 \,\mu$ s, Duty Cycle $\leq 2\%$.
- 4. Guaranteed by design, not subject to production
- **5.** EAS condition : Tj=25 $^{\circ}\text{C}$,VDD=50V,VG=10V,L=0.5mH,Rg=25 Ω



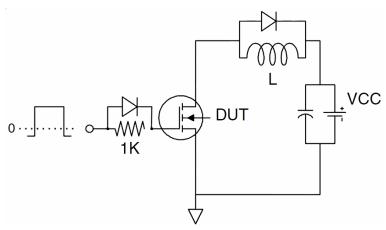
NCE0110AK

Test Circuit

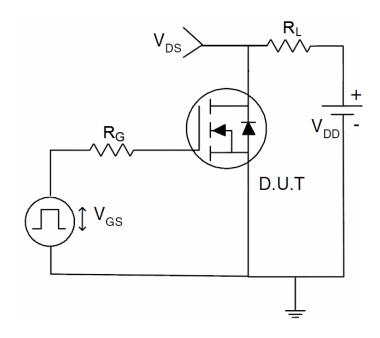
1) E_{AS} test Circuit



2) Gate charge test Circuit



3) Switch Time Test Circuit



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Typical Electrical and Thermal Characteristics (Curves)

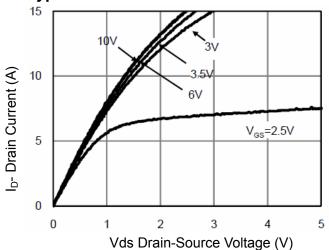


Figure 1 Output Characteristics

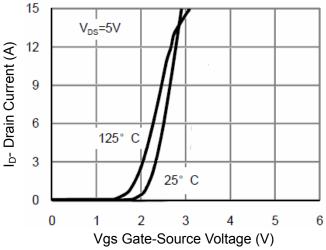


Figure 2 Transfer Characteristics

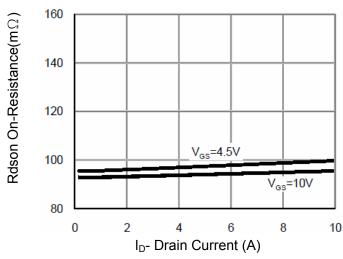


Figure 3 Rdson- Drain Current

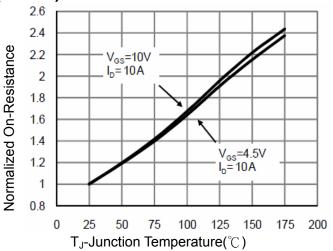


Figure 4 Rdson-JunctionTemperature

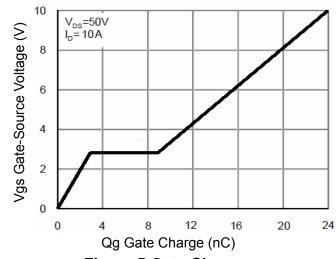


Figure 5 Gate Charge

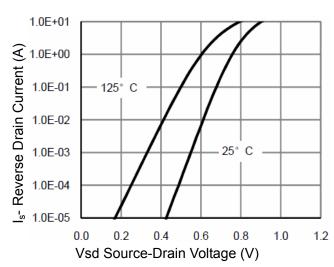


Figure 6 Source- Drain Diode Forward



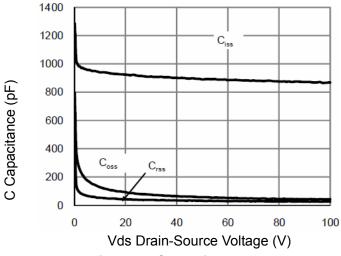


Figure 7 Capacitance vs Vds

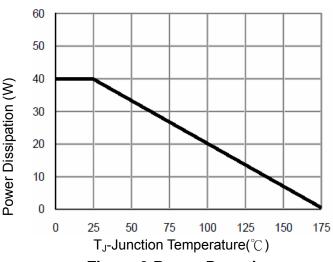


Figure 9 Power De-rating

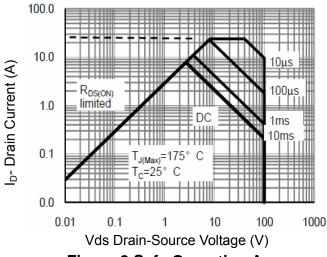


Figure 8 Safe Operation Area

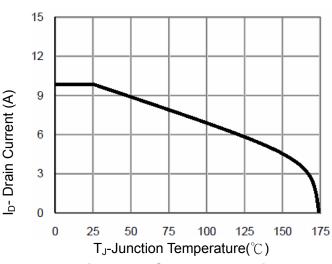


Figure 10 Current De-rating

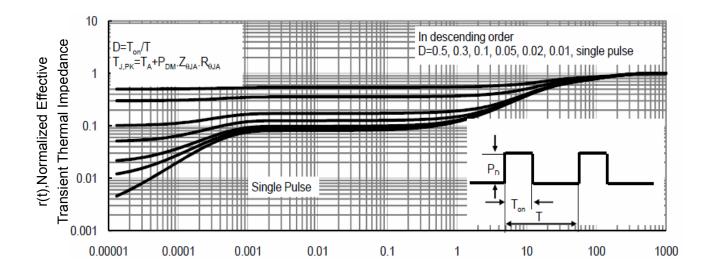
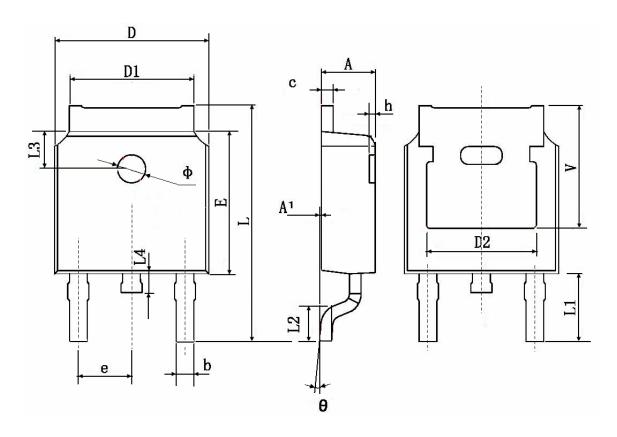


Figure 11 Normalized Maximum Transient Thermal Impedance

Square Wave Pluse Duration(sec)



TO-252 Package Information



Symbol	Dimensions I	n Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
А	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	4.830 TYP.		0.190 TYP.		
Е	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900 TYP.		0.114 TYP.		
L2	1.400	1.700	0.055	0.067	
L3	1.600 TYP.		0.063 TYP.		
L4	0.600	1.000	0.024	0.039	
Ф	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350	5.350 TYP. 0.211 TYP.		TYP.	



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